


CYStek Electronics Corp.

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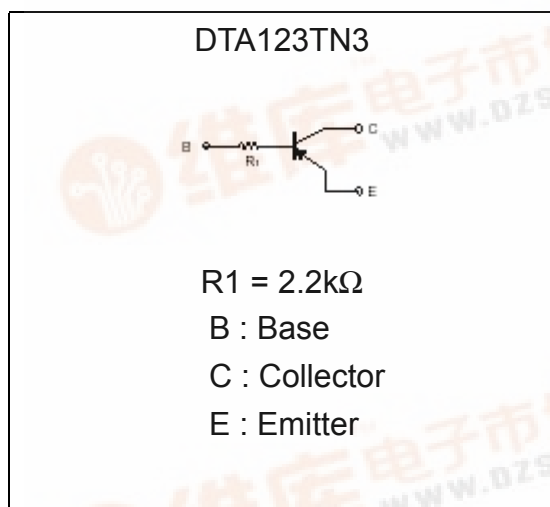
PNP Digital Transistors (Built-in Resistors)

DTA123TN3

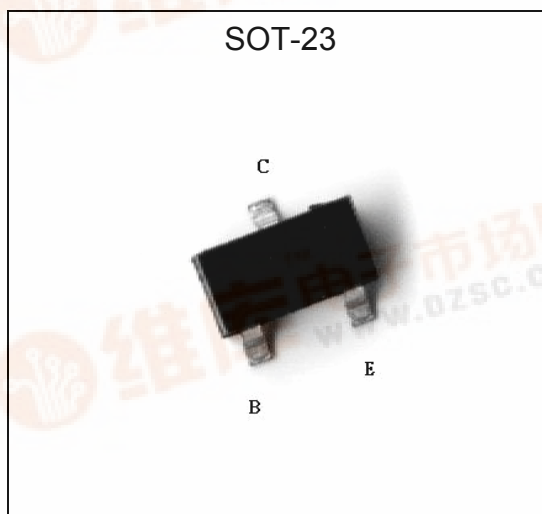
Features

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.
- Complements the DTC123TN3

Equivalent Circuit



Outline



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _C	-100	mA
Power Dissipation	P _d	200	mW
Thermal Resistance, Junction to Ambient	R _{θJA}	625	°C/W
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55~+150	°C

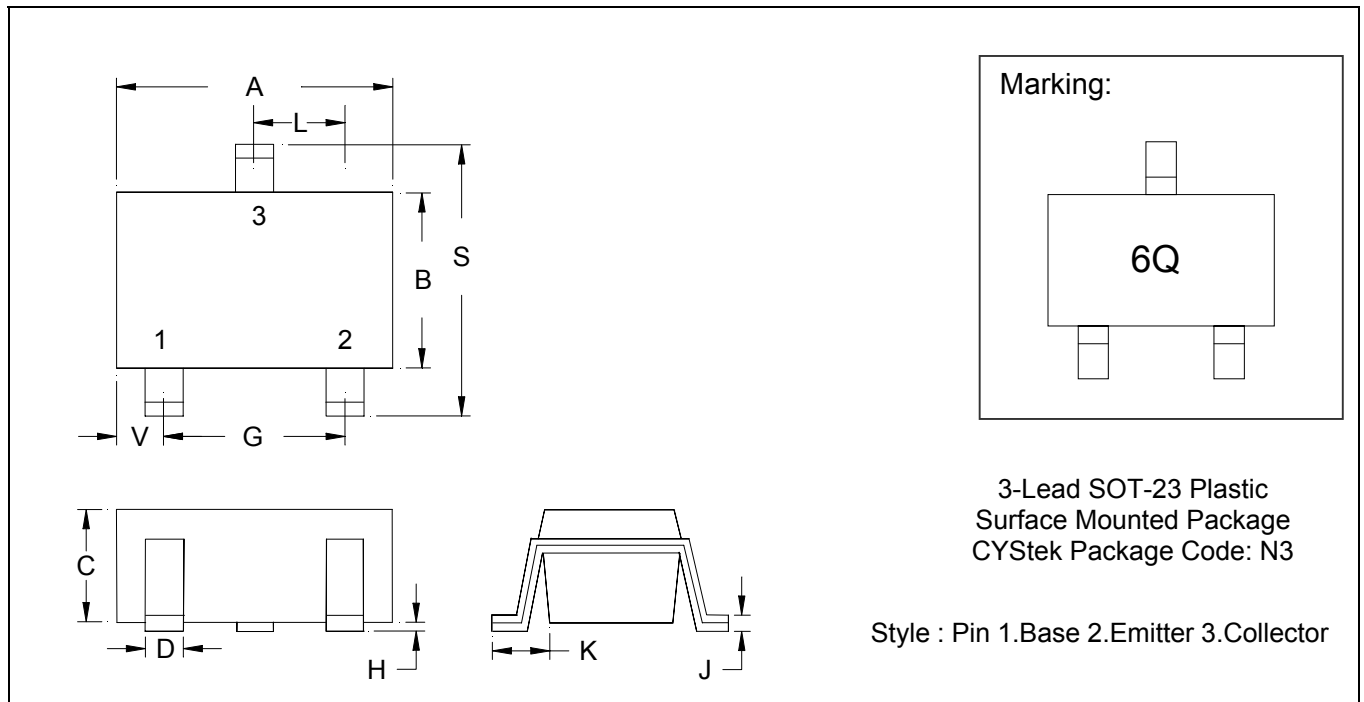
**Characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-	-	V	I _C =-50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-50	-	-	V	I _C =-1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-	-	V	I _E =-50μA
Collector-Base Cutoff Current	I _{CBO}	-	-	-0.5	μA	V _{CB} =-50V
Emitter-Base Cutoff Current	I _{EBO}	-	-	-0.5	μA	V _{EB} =-4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	0.1	-0.3	V	I _C =-5mA, I _B =-0.25mA
DC Current Gain	h _{FE}	100	-	600	-	V _{CE} =-5V, I _C =-1mA
Input Resistance	R	1.54	2.2	2.86	kΩ	-
Transition Frequency	f _T	-	250	-	MHz	V _{CE} =-10V, I _C =-5mA, f=100MHz*

* Transition frequency of the device



SOT-23 Dimension



*:Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0034	0.0070	0.085	0.177
B	0.0472	0.0630	1.20	1.60	K	0.0128	0.0266	0.32	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1083	2.10	2.75
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0005	0.0040	0.013	0.10					

Notes : 1.Controlling dimension : millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material :

- Lead : 42 Alloy ; solder plating
- Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0

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